4-bit dual supply translating transceiver; 3-state Rev. 1 — 25 September 2017 Pr

Product data sheet

1 General description

The 74AVC4T774PW is a 4-bit, dual supply transceiver that enables bidirectional level translation. It features eight 1-bit input-output ports (An and Bn), four direction control inputs (DIR1, DIR2, DIR3 and DIR4), an output enable input (\overline{OE}) and dual supply pins ($V_{CC(A)}$ and $V_{CC(B)}$). Both $V_{CC(A)}$ and $V_{CC(B)}$ can be supplied at any voltage between 0.8 V and 1.95 V for translating between the 0.8 V, 1.2 V, 1.5 V and 1.8 V supply voltage nodes or 1.1 V to 3.6 V for translating between the 1.2 V, 1.5 V, 1.8 V, 2.5 V and 3.3 V supply voltage nodes. Pins An, \overline{OE} and DIRn are referenced to $V_{CC(A)}$ and pins Bn are referenced to $V_{CC(B)}$. A HIGH on DIRn allows transmission from An to Bn and a LOW on DIRn allows transmission from Bn to An. The output enable input (\overline{OE}) can be used to disable the outputs so the buses are effectively isolated.

The device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either V_{CC(A)} or V_{CC(B)} are at GND level, both An and Bn are in the high-impedance OFF-state.

2 Features and benefits

- Wide supply voltage range:
 - V_{CC(A)} and V_{CC(B)}: 0.8 V to 1.95 V or 1.1 V to 3.6 V
- · Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114E Class 3B exceeds 8000 V
 - CDM JESD22-C101C exceeds 1500 V
- Maximum data rates:
 - 380 Mbit/s (≥ 1.8 V to 3.3 V translation)
 - 200 Mbit/s (≥ 1.1 V to 3.3 V translation)
 - 200 Mbit/s (\geq 1.1 V to 2.5 V translation)
 - 200 Mbit/s (≥ 1.1 V to 1.8 V translation)
 - 150 Mbit/s (≥ 1.1 V to 1.5 V translation)
 - 100 Mbit/s (≥ 1.1 V to 1.2 V translation)
- Suspend mode
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- I_{OFF} circuitry provides partial Power-down mode operation

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4-bit dual supply translating transceiver; 3-state

Specified from -40 °C to +85 °C and -40 °C to +125 °C

3 Ordering information

Table 1. Ordering information								
Type number Package								
	Temperature range	Name	Description	Version				
74AVC4T774PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1				

4 Marking

Table 2. Marking codes	
Type number	Marking code
74AVC4T774PW	VC4T774

5 Functional diagram

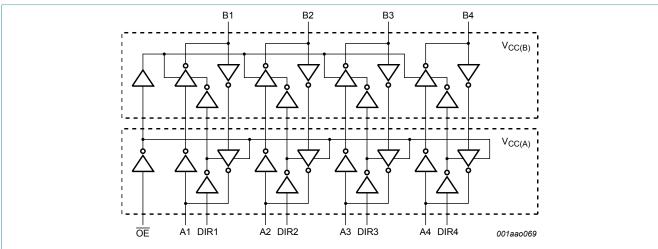
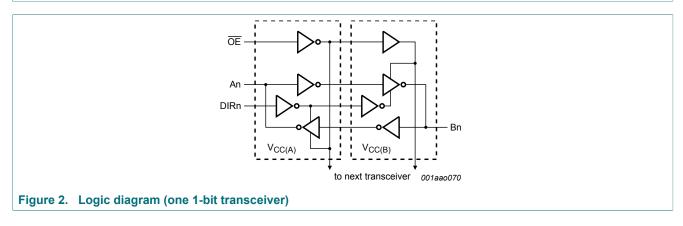


Figure 1. Logic symbol



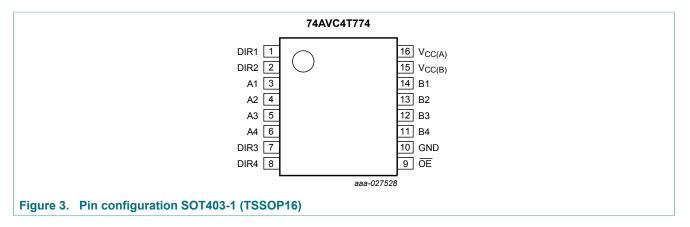
74AVC4T774PW Product data sheet

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4-bit dual supply translating transceiver; 3-state

6 Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
V _{CC(A)}	16	supply voltage A (An, $\overline{\text{OE}}$ and DIRn inputs are referenced to $V_{\text{CC}(A)})$
DIR1, DIR2, DIR3, DIR4	1, 2, 7, 8	direction control input
A1, A2, A3, A4	3, 4, 5, 6	data input or output
GND	10	ground (0 V)
B1, B2, B3, B4	14, 13, 12, 11	data input or output
ŌĒ	9	output enable input (active LOW)
V _{CC(B)}	15	supply voltage B (Bn pins are referenced to $V_{CC(B)}$)

4-bit dual supply translating transceiver; 3-state

Functional description 7

Table 4. Function table ^{[1] [2]}

Supply voltage	Input					Input/output		
V _{CC(A)} , V _{CC(B)}	OE	DIR1	DIR2	DIR3	DIR4	An	Bn	
0.8 V to 3.6 V	L	L	Х	Х	Х	A1 = B1	input B1	
0.8 V to 3.6 V	L	Н	Х	Х	Х	input A1	B1 = A1	
0.8 V to 3.6 V	L	Х	L	Х	Х	A2 = B2	input B2	
0.8 V to 3.6 V	L	Х	Н	Х	Х	input A2	B2 = A2	
0.8 V to 3.6 V	L	Х	Х	L	Х	A3 = B3	input B3	
0.8 V to 3.6 V	L	Х	Х	Н	Х	input A3	B3 = A3	
0.8 V to 3.6 V	L	Х	Х	Х	L	A4 = B4	input B4	
0.8 V to 3.6 V	L	Х	Х	Х	Н	input A4	B4 = A4	
0.8 V to 3.6 V	Н	Х	Х	Х	Х	Z	Z	
GND ^[3]	Х	Х	Х	Х	Х	Z	Z	

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] The An, DIRn and \overline{OE} input circuit is referenced to V_{CC(A)}. The Bn input circuit is referenced to V_{CC(B)}. [3] If at least one of V_{CC(A)} or V_{CC(B)} is at GND level, the device goes into suspend mode.

Limiting values 8

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC(A)}	supply voltage A			-0.5	+4.6	V
V _{CC(B)}	supply voltage B			-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{ОК}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1] [2] [3]	-0.5	V _{CCO} + 0.5	V
		Suspend or 3-state mode	[1]	-0.5	+4.6	V
lo	output current	V_{O} = 0 V to V_{CCO}	[2]	-	±50	mA
I _{CC}	supply current	$I_{CC(A)}$ or $I_{CC(B)}$		-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[4]	-	500	mW

The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed. [1]

 V_{CCO} is the supply voltage associated with the output port.

 $\begin{array}{l} [2] \quad V_{CCO} \text{ is the supply voltage associated with the output port.} \\ [3] \quad V_{CCO} + 0.5 \ V \text{ should not exceed 4.6 V.} \\ [4] \quad For TSSOP16 package: above 60 \ ^{\circ}C \ the value of P_{tot} \ derates linearly at 5.5 \ mW/K. \end{array}$

74AVC4T774PW **Product data sheet**

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Rev. 1 - 25 September 2017

4-bit dual supply translating transceiver; 3-state

Recommended operating conditions 9

Tuble 0. Recommended operating conditions	Table 6.	Recommended	operating	conditions
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Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC(A)}	supply voltage A			0.8	3.6	V
V _{CC(B)}	supply voltage B			0.8	3.6	V
VI	input voltage			0	3.6	V
Vo	output voltage	Active mode	[1]	0	V _{cco}	V
		Suspend or 3-state mode		0	3.6	V
T _{amb}	ambient temperature			-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CCI} =0.8 V to 3.6 V	[2]	-	10	ns/V

[1] V_{CCO} is the supply voltage associated with the output port.

[2] V_{CCI} is the supply voltage associated with the input port.

10 Static characteristics

Table 7. Typical static characteristics at T_{amb} = 25 °C ^{[1] [2]}

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}				
	output voltage	I_{O} = -1.5 mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 0.8 V	-	0.69	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$				
	output voltage	I_{O} = 1.5 mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 0.8 V	-	0.07	-	V
lı	input leakage current	DIRn, \overline{OE} input; V _I = 0 V or 3.6 V; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V	-	±0.025	±0.25	μA
I _{OZ}	OFF-state	A or B port; $V_0 = 0$ V or V_{CCO} ; $V_{CC(A)} = V_{CC(B)} = 3.6$ V ^[3]	^{3]} _	±0.5	±2.5	μA
	output current	suspend mode A port; $V_O = 0 V \text{ or } V_{CCO}$; $V_{CC(A)} = 3.6 V$; $V_{CC(B)} = 0 V$	<u> </u>	±0.5	±2.5	μA
		suspend mode B port; $V_O = 0 V$ or V_{CCO} ; ^[3] $V_{CC(A)} = 0 V$; $V_{CC(B)} = 3.6 V$	3] _	±0.5	±2.5	μA
I _{OFF}	power-off leakage	A port; V ₁ or V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0.8 V to 3.6 V	-	±0.1	±1	μA
	current	B port; V ₁ or V ₀ = 0 V to 3.6 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0.8 V to 3.6 V	-	±0.1	±1	μA
Cı	input capacitance	DIRn, \overline{OE} input; V _I = 0 V or 3.3 V; V _{CC(A)} = V _{CC(B)} = 3.3 V	-	2.0	-	pF
C _{I/O}	input/output capacitance	A and B port; V _O = 3.3 V or 0 V; V _{CC(A)} = V _{CC(B)} = 3.3 V	-	4.0	-	pF

[1] V_{CCO} is the supply voltage associated with the output port.

[2] V_{CCI} is the supply voltage associated with the data input port. [3] For I/O ports, the parameter I_{OZ} includes the input leakage current.

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Rev. 1 - 25 September 2017

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4-bit dual supply translating transceiver; 3-state

Table 8. Static characteristics ^{[1] [2]}

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to	o +85 °C	-40 °C to	• +125 ℃	Unit
			Min	Max	Min	Max	
V _{IH}	HIGH-level	data input					
	input voltage	V _{CCI} = 0.8 V	0.70V _{CCI}	-	0.70V _{CCI}	-	V
		V _{CCI} = 1.1 V to 1.95 V	0.65V _{CCI}	-	0.65V _{CCI}	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.6	-	1.6	-	V
		V _{CCI} = 3.0 V to 3.6 V	2	-	2	-	V
		DIRn, OE input					
		V _{CC(A)} = 0.8 V	0.70V _{CC(A)}	-	0.70V _{CC(A)}	-	V
		V _{CC(A)} = 1.1 V to 1.95 V	0.65V _{CC(A)}	-	0.65V _{CC(A)}	-	V
		V _{CC(A)} = 2.3 V to 2.7 V	1.6	-	1.6	-	V
		V _{CC(A)} = 3.0 V to 3.6 V	2	-	2	-	V
V _{IL}	LOW-level	data input					
	input voltage	V _{CCI} = 0.8 V	-	0.30V _{CCI}	-	0.30V _{CCI}	V
		V _{CCI} = 1.1 V to 1.95 V	-	0.35V _{CCI}	-	0.35V _{CCI}	V
		V _{CCI} = 2.3 V to 2.7 V	-	0.7	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V	-	0.8	-	0.8	V
		DIRn, OE input				Image: Circle in the constraint of	
		V _{CC(A)} = 0.8 V	-	0.30V _{CC(A)}	-		V
		V _{CC(A)} = 1.1 V to 1.95 V	-	0.35V _{CC(A)}	-		V
		$V_{CC(A)}$ = 2.3 V to 2.7 V	-	0.7	-	0.7	V
		V _{CC(A)} = 3.0 V to 3.6 V	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$					
	output voltage	I _O = -100 μA; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V	V _{CCO} - 0.1	-	V _{CCO} - 0.1	-	V
		I _O = -3 mA; V _{CC(A)} = V _{CC(B)} = 1.1 V	0.85	-	0.85	-	V
		I _O = -6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V	1.05	-	1.05	-	V
		I _O = -8 mA; V _{CC(A)} = V _{CC(B)} = 1.65 V	1.2	-	1.2	-	V
		I _O = -9 mA; V _{CC(A)} = V _{CC(B)} = 2.3 V	1.75	-	1.75	-	V
		I_{O} = -12 mA; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.0 V	2.3	-	2.3	-	V

74AVC4T774PW

4-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
				Min	Max	Min	Max	ν ν ν ν ν ν ν ν ν ν μΑ μΑ
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}						
	output voltage	I_{O} = 100 µA; $V_{CC(A)} = V_{CC(B)} = 0.8$ V to 3.6 V		-	0.1	-	0.1	V
		I_{O} = 3 mA; $V_{CC(A)} = V_{CC(B)}$ = 1.1 V		-	0.25	-	0.25	V
		I _O = 6 mA; V _{CC(A)} = V _{CC(B)} = 1.4 V		-	0.35	-	0.35	V
		I _O = 8 mA; V _{CC(A)} = V _{CC(B)} = 1.65 V		-	0.45	-	0.45	V
		I _O = 9 mA; V _{CC(A)} = V _{CC(B)} = 2.3 V		-	0.55	-	0.55	V
		I_{O} = 12 mA; $V_{CC(A)} = V_{CC(B)}$ = 3.0 V		-	0.7	-	0.7	V
lı	input leakage current	DIRn, \overline{OE} input; V _I = 0 V or 3.6 V; V _{CC(A)} = V _{CC(B)} = 0.8 V to 3.6 V		-	±1	-	±5	μA
I _{OZ}	OFF-state output current	A or B port; $V_O = 0 V$ or V_{CCO} ; $V_{CC(A)} = V_{CC(B)} = 3.6 V$	[3]	-	±5	-	±30	μA
		suspend mode A port; $V_O = 0 V$ or V_{CCO} ; $V_{CC(A)} = 3.6 V$; $V_{CC(B)} = 0 V$	[3]	-	±5	-	±30	μA
		suspend mode B port; $V_O = 0 V$ or V_{CCO} ; $V_{CC(A)} = 0 V$; $V_{CC(B)} = 3.6 V$	[3]	-	±5	-	±30	μA
I _{OFF}	power-off leakage	A port; V ₁ or V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0.8 V to 3.6 V		-	±5	-	±30	μA
	current	B port; V _I or V _O = 0 V to 3.6 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0.8 V to 3.6 V		-	±5	-	±30	μA

74AVC4T774PW

4-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions	-40 °C to +85 °C -40 °C to		o +125 °C		
			Min	Мах	Min	Мах	
I _{CC}	supply current	A port; $V_I = 0 V$ or V_{CCI} ; $I_O = 0 A$					
		V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V	-	10	-	55	μA
		V _{CC(A)} = 1.1 V to 3.6 V; V _{CC(B)} = 1.1 V to 3.6 V	-	8	-	50	μA
		V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V	-	8	-	50	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V	-2	-	-12	-	μA
		B port; $V_I = 0 V$ or V_{CCI} ; $I_O = 0 A$					
		V _{CC(A)} = 0.8 V to 3.6 V; V _{CC(B)} = 0.8 V to 3.6 V	-	10	-	55	μA
		V _{CC(A)} = 1.1 V to 3.6 V; V _{CC(B)} = 1.1 V to 3.6 V	-	8	-	50	μA
		V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V	-2	-	-12	-	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 3.6 V	-	8	-	50	μA
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0$ A; $V_I = 0$ V or V_{CCI} ; $V_{CC(A)} = 0.8$ V to 3.6 V; $V_{CC(B)} = 0.8$ V to 3.6 V	-	20	-	70	μA
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0 A$; $V_I = 0 V \text{ or } V_{CCI}$; $V_{CC(A)} = 1.1 V \text{ to } 3.6 V$; $V_{CC(B)} = 1.1 V \text{ to } 3.6 V$	-	16	-	65	μA
ΔI _{CC}	additional supply current	V_{I} = 3.0 V; $V_{CC(A)}$ = $V_{CC(B)}$ = 3.6 V	-	500	-	650	μA

V_{CCO} is the supply voltage associated with the output port.
 V_{CCI} is the supply voltage associated with the data input port.
 For I/O ports, the parameter I_{OZ} includes the input leakage current.

Table 9. Typical total supply current (I_{CC(A)} + I_{CC(B)})

V _{CC(A)}	V _{CC(B)}	V _{CC(B)}							
	0 V	0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V		
0 V	0	0.1	0.1	0.1	0.1	0.1	0.1	μA	
0.8 V	0.1	0.1	0.1	0.1	0.1	0.3	1.6	μA	
1.2 V	0.1	0.1	0.1	0.1	0.1	0.1	0.8	μA	
1.5 V	0.1	0.1	0.1	0.1	0.1	0.1	0.4	μA	
1.8 V	0.1	0.1	0.1	0.1	0.1	0.1	0.2	μA	
2.5 V	0.1	0.3	0.1	0.1	0.1	0.1	0.1	μA	
3.3 V	0.1	1.6	0.8	0.4	0.2	0.1	0.1	μA	

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Rev. 1 — 25 September 2017

4-bit dual supply translating transceiver; 3-state

11 Dynamic characteristics

Table 10. Typical power dissipation capacitance at $V_{CC(A)} = V_{CC(B)}$ and $T_{amb} = 25 \ ^{\circ}C^{[1][2]}$ Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions			V _{CC(A)} =	= V _{CC(B)}			Unit
			0.8 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
C _{PD}	power dissipation capacitance	A port: (direction An to Bn); output enabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		A port: (direction An to Bn); output disabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		A port: (direction Bn to An); output enabled	9.5	9.7	9.8	9.9	10.7	11.9	pF
		A port: (direction Bn to An); output disabled	0.6	0.6	0.6	0.6	0.7	0.7	pF
		B port: (direction An to Bn); output enabled	9.5	9.7	9.8	9.9	10.7	11.9	pF
		B port: (direction An to Bn); output disabled	0.6	0.6	0.6	0.6	0.7	0.7	pF
		B port: (direction Bn to An); output enabled	0.2	0.2	0.2	0.2	0.3	0.4	pF
		B port: (direction Bn to An); output disabled	0.2	0.2	0.2	0.2	0.3	0.4	pF

- [1] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).
 - $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$
 - f_i = input frequency in MHz;
 - f_o = output frequency in MHz;
 - C_L = load capacitance in pF;
 - V_{CC} = supply voltage in V;
- N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs. [2] $f_i = 10 \text{ MHz}; V_I = \text{GND to } V_{CC}; t_r = t_f = 1 \text{ ns}; C_L = 0 \text{ pF}; R_L = \infty \Omega.$

4-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions		Vcc	С(В)		Unit
			0.8 V	1.2 V	1.5 V	1.8 V	
t _{pd}	propagation delay	An to Bn	14.5	7.3	6.5	6.2	ns
		Bn to An	14.5	12.7	12.4	12.3	ns
t _{dis}	disable time	OE to An	14.3	14.3	14.3	14.3	ns
		OE to Bn	17.0	9.9	9.0	9.4	ns
t _{en}	enable time	OE to An	18.2	18.2	18.2	18.2	ns
		OE to Bn	19.2	10.7	9.8	9.6	ns

Table 11. Typical dynamic characteristics at $V_{CC(A)} = 0.8 \text{ V}$ and $T_{amb} = 25 \text{ °C}^{[1]}$ Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6; for waveforms see Figure 4 and Figure 5

 $[1] \ t_{pd} \ is the same as \ t_{PLH} \ and \ t_{PHL}; \ t_{dis} \ is the same as \ t_{PLZ} \ and \ t_{PHZ}; \ t_{en} \ is the same as \ t_{PZH}.$

Table 12. Typical dynamic characteristics at $V_{CC(B)}$ = 0.8 V and T_{amb} = 25 °C $^{[1]}$

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6; for waveforms see Figure 4 and Figure 5

Symbol	Parameter	Conditions		V _{CC}	C(A)		Unit
			0.8 V	1.2 V	1.5 V	1.8 V	
t _{pd}	propagation delay	An to Bn	14.5	12.7	12.4	12.3	ns
		Bn to An	14.5	7.3	6.5	6.2	ns
t _{dis}	disable time	OE to An	14.3	5.5	4.1	4.0	ns
		OE to Bn	17.0	13.8	13.4	13.1	ns
t _{en}	enable time	OE to An	18.2	5.6	4.0	3.2	ns
		OE to Bn	19.2	14.6	14.1	13.9	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

74AVC4T774PW

4-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions					Vc	C(B)					Unit
			1.2 V	±0.1 V	1.5 V	±0.1 V	1.8 V ±	±0.15 V	2.5 V	±0.2 V	3.3 V ±0.3 V		
			Min	Max	Min	Max	Min	Мах	Min	Мах	Min	Max	-
$V_{CC(A)} = $	1.1 V to 1.3 V	-											
t _{pd}	propagation	An to Bn	2.0	10.5	1.3	7.8	1.2	6.9	1.0	5.9	0.8	5.7	ns
	delay	Bn to An	2.0	10.5	1.5	9.9	1.5	9.7	1.4	9.4	1.4	9.3	ns
t _{dis}	disable time	OE to An	2.0	10.0	2.0	10.0	2.0	10.0	2.0	10.0	2.0	10.0	ns
		OE to Bn	2.0	11.1	2.0	8.6	1.0	8.0	0.7	7.0	1.0	8.0	ns
t _{en}	enable time	OE to An	2.0	13.5	2.0	13.5	2.0	13.5	2.0	13.5	2.0	13.5	ns
		OE to Bn	2.0	15.0	2.0	11.0	2.0	9.4	1.0	7.8	1.0	7.4	ns
$V_{CC(A)} = $	1.4 V to 1.6 V				1		1	1		1	I	1	
t _{pd}	propagation	An to Bn	1.5	9.9	1.0	7.1	1.0	6.0	0.5	4.8	0.5	4.3	ns
	delay	Bn to An	1.3	7.8	1.0	7.1	0.9	6.9	0.8	6.6	0.6	6.5	ns
t _{dis}	disable time	OE to An	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	ns
		OE to Bn	2.0	10.2	1.5	7.5	0.9	7.2	0.4	6.2	0.4	6.1	ns
t _{en}	enable time	OE to An	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	ns
		OE to Bn	2.0	14.4	1.4	7.9	1.3	7.7	1.1	6.4	1.1	5.6	ns
$V_{CC(A)} = $	1.65 V to 1.95	v	1	1	1	1	<u>.</u>	1	1	1	1	1	
t _{pd}	propagation	An to Bn	1.5	9.7	0.9	6.9	0.8	5.7	0.5	4.5	0.3	4.0	ns
	delay	Bn to An	1.2	6.9	1.0	6.0	0.8	5.7	0.5	5.5	0.5	5.3	ns
t _{dis}	disable time	OE to An	0.5	5.7	0.5	5.7	0.5	5.7	0.5	5.7	0.5	5.7	ns
		OE to Bn	2.0	9.9	1.5	7.0	0.8	6.9	0.2	5.8	0.2	5.9	ns
t _{en}	enable time	OE to An	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	ns
		OE to Bn	1.5	13.9	1.2	7.2	1.2	6.9	0.8	5.4	0.6	5.0	ns
$V_{CC(A)} = 2$	2.3 V to 2.7 V		1						1	1		1	
t _{pd}	propagation	An to Bn	1.4	9.4	0.8	6.6	0.5	5.5	0.4	4.2	0.2	3.7	ns
	delay	Bn to An	1.0	5.9	0.5	4.8	0.5	4.5	0.4	4.2	0.3	3.9	ns
t _{dis}	disable time	OE to An	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	ns
		OE to Bn	2.0	9.3	1.5	6.7	0.7	6.3	0.2	5.0	0.2	5.7	ns
t _{en}	enable time	OE to An	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	ns
		OE to Bn	1.5	13.6	1.0	6.8	1.0	6.0	0.8	4.6	0.6	4.2	ns

Table 13. Dynamic characteristics for temperature range -40 °C to +85 °C ^[1] Voltages are referenced to GND (ground = 0 V): for test circuit see Figure 6: for waveforms see Figure 4 and Figure 5

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4-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions					Vc	C(B)					Unit
			1.2 V	±0.1 V	1.5 V ±0.1 V		1.8 V ±0.15 V		2.5 V ±0.2 V		3.3 V ±0.3 V		
			Min	Max	Min	Max	Min	Мах	Min	Max	Min	Max	
$V_{CC(A)} = $	3.0 V to 3.6 V	1			1	1	1	1	1	1	1	-	
t _{pd}	propagation	An to Bn	1.4	9.3	0.6	6.5	0.5	5.3	0.3	3.9	0.2	3.5	ns
	delay	Bn to An	0.8	5.7	0.5	4.3	0.3	4.0	0.2	3.7	0.2	3.5	ns
t _{dis}	disable time	OE to An	0.2	4.5	0.2	4.5	0.2	4.5	0.2	4.5	0.2	4.5	ns
		OE to Bn	2.0	9.0	1.5	6.4	0.7	6.1	0.2	4.8	0.2	5.6	ns
t _{en}	enable time	OE to An	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	ns
		OE to Bn	1.5	13.4	1.0	6.7	1.0	5.9	0.7	4.4	0.5	4.0	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

Table 14. Dynamic characteristics for temperature range -40 °C to +125 °C ^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6; for waveforms see Figure 4 and Figure 5

Symbol	Parameter	Conditions	_				Vc	С(В)					Unit
			1.2 V	±0.1 V	1.5 V	±0.1 V	1.8 V ±	±0.15 V	2.5 V	±0.2 V	3.3 V	±0.3 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
$V_{CC(A)} = $	1.1 V to 1.3 V			1	1	1							
t _{pd}	propagation	An to Bn	2.0	12.1	1.3	9.0	1.2	8.0	1.0	6.8	0.8	6.6	ns
	delay	Bn to An	2.0	12.1	1.5	11.4	1.5	11.2	1.4	10.9	1.4	10.7	ns
t _{dis}	disable time	OE to An	2.0	11.5	2.0	11.5	2.0	11.5	2.0	11.5	2.0	11.5	ns
		OE to Bn	2.0	12.8	2.0	9.9	1.0	9.2	0.7	8.1	1.0	9.2	ns
t _{en}	enable time	OE to An	2.0	15.6	2.0	15.6	2.0	15.6	2.0	15.6	2.0	15.6	ns
		OE to Bn	2.0	17.3	2.0	12.7	2.0	10.9	1.0	9.0	1.0	8.6	ns
$V_{CC(A)} = $	1.4 V to 1.6 V	-		1			1		1		1	1	
t _{pd}	propagation	An to Bn	1.5	11.4	1.0	8.2	1.0	6.9	0.5	5.6	0.5	5.0	ns
	delay	Bn to An	1.3	9.0	1.0	8.2	0.9	8.0	0.8	7.6	0.6	7.5	ns
t _{dis}	disable time	OE to An	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	1.0	6.9	ns
		OE to Bn	2.0	11.8	1.5	8.7	0.9	8.3	0.4	7.2	0.4	7.1	ns
t _{en}	enable time	OE to An	1.0	8.7	1.0	8.7	1.0	8.7	1.0	8.7	1.0	8.7	ns
		OE to Bn	2.0	16.6	1.4	9.1	1.3	8.9	1.1	7.4	1.1	6.5	ns

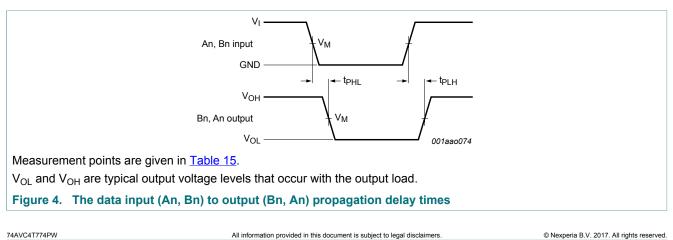
74AVC4T774PW

4-bit dual supply translating transceiver; 3-state

Symbol	Parameter	Conditions					Vc	C(B)					Unit
			1.2 V	±0.1 V	1.5 V	±0.1 V	1.8 V :	±0.15 V	2.5 V	±0.2 V	3.3 V ±0.3 V		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	-
V _{CC(A)} =	1.65 V to 1.95	V		1	1	1	1		1		1		_
t _{pd}	propagation	An to Bn	1.5	11.2	0.9	8.0	0.8	6.6	0.5	5.2	0.3	4.6	ns
	delay	Bn to An	1.2	8.0	1.0	6.9	0.8	6.6	0.5	6.4	0.5	6.1	ns
t _{dis}	disable time	OE to An	0.5	6.6	0.5	6.6	0.5	6.6	0.5	6.6	0.5	6.6	ns
		OE to Bn	2.0	11.4	1.5	8.1	0.8	8.0	0.2	6.7	0.2	6.8	ns
t _{en}	enable time	OE to An	1.0	7.8	1.0	7.8	1.0	7.8	1.0	7.8	1.0	7.8	ns
		OE to Bn	1.5	16.0	1.2	8.3	1.2	8.0	0.8	6.3	0.6	5.8	ns
$V_{CC(A)} = 2$	2.3 V to 2.7 V		1	1		1	1		1	1	1		
t _{pd}	propagation delay	An to Bn	1.4	10.9	0.8	7.6	0.5	6.4	0.4	4.9	0.2	4.3	ns
		Bn to An	1.0	6.8	0.5	5.6	0.5	5.2	0.4	4.9	0.3	4.5	ns
t _{dis}	disable time	OE to An	0.2	4.6	0.2	4.6	0.2	4.6	0.2	4.6	0.2	4.6	ns
		OE to Bn	2.0	10.7	1.5	7.8	0.7	7.3	0.2	5.8	0.2	6.6	ns
t _{en}	enable time	OE to An	0.6	5.2	0.6	5.2	0.6	5.2	0.6	5.2	0.6	5.2	ns
		OE to Bn	1.5	15.7	1.0	7.9	1.0	6.9	0.8	5.3	0.6	4.9	ns
$V_{CC(A)} = $	3.0 V to 3.6 V		1	1	1	1			1		1		
t _{pd}	propagation	An to Bn	1.4	10.7	0.6	7.5	0.5	6.1	0.3	4.5	0.2	4.1	ns
	delay	Bn to An	0.8	6.6	0.5	5.0	0.3	4.6	0.2	4.3	0.2	4.1	ns
t _{dis}	disable time	OE to An	0.2	5.2	0.2	5.2	0.2	5.2	0.2	5.2	0.2	5.2	ns
		OE to Bn	2.0	10.4	1.5	7.4	0.7	7.1	0.2	5.6	0.2	6.5	ns
t _{en}	enable time	OE to An	0.5	4.6	0.5	4.6	0.5	4.6	0.5	4.6	0.5	4.6	ns
		OE to Bn	1.5	15.5	1.0	7.8	1.0	6.8	0.7	5.1	0.5	4.6	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

11.1 Waveforms and test circuit



Product data sheet

Rev. 1 — 25 September 2017

74AVC4T774PW

4-bit dual supply translating transceiver; 3-state

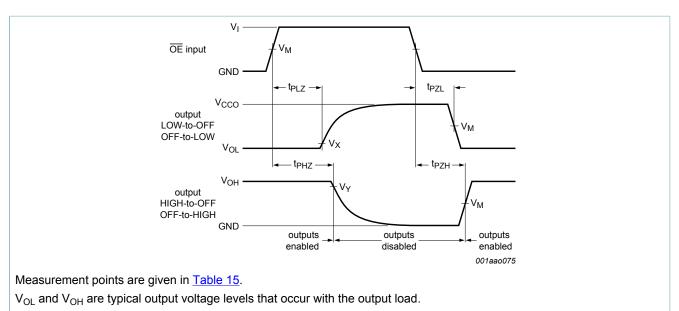


Figure 5. Enable and disable times

Table 15. Measurement points

Supply voltage	Input ^[1]	Output ^[2]		
V _{CC(A)} , V _{CC(B)}	V _M	V _M	V _X	V _Y
0.8 V to 1.6 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.1 V	V _{OH} - 0.1 V
1.65 V to 2.7 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.15 V	V _{OH} - 0.15 V
3.0 V to 3.6 V	0.5V _{CCI}	0.5V _{CCO}	V _{OL} + 0.3 V	V _{OH} - 0.3 V

74AVC4T774PW

4-bit dual supply translating transceiver; 3-state

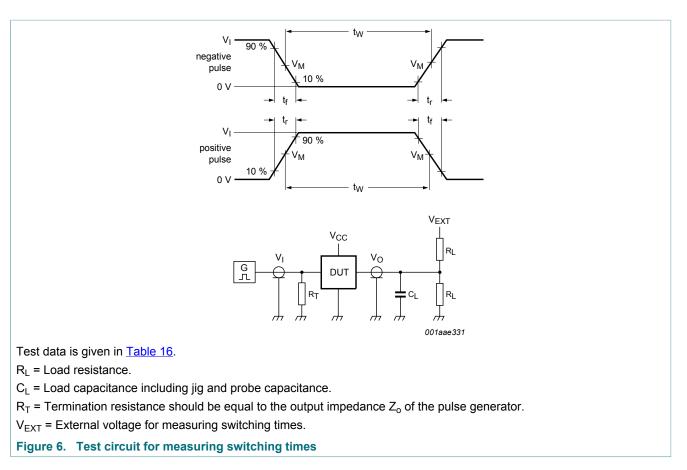
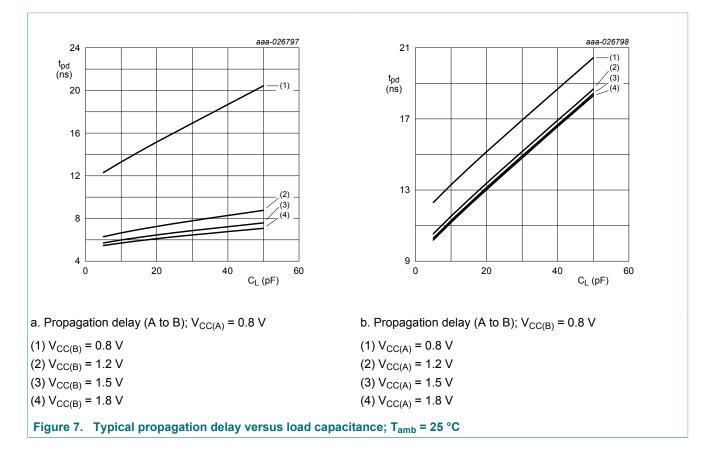


Table 16. Test data

Supply voltage			Load		V _{EXT}				
V _{CC(A)} , V _{CC(B)}	V _I ^[1]	Δt/ΔV ^[2]	CL	RL	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t_{PZL}, t_{PLZ} ^[3]		
0.8 V to 1.6 V	V _{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V _{CCO}		
1.65 V to 2.7 V	V _{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V _{CCO}		
3.0 V to 3.6 V	V _{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2V _{CCO}		

15/24

4-bit dual supply translating transceiver; 3-state

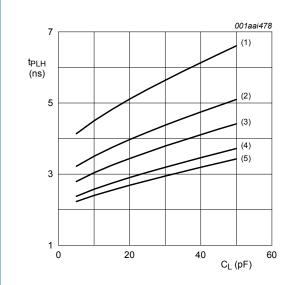


11.2 Typical propagation delay characteristics

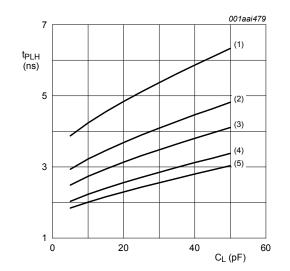
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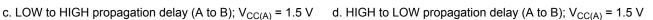
001aai491

4-bit dual supply translating transceiver; 3-state



a. LOW to HIGH propagation delay (A to B); $V_{CC(A)} = 1.2 V$



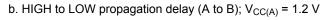


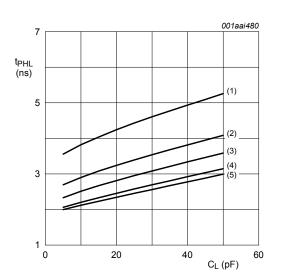
- (1) $V_{CC(B)} = 1.2 V$
- (2) V_{CC(B)} = 1.5 V (3) V_{CC(B)} = 1.8 V
- (4) V_{CC(B)} = 2.5 V
- (5) V_{CC(B)} = 3.3 V

Figure 8. Typical propagation delay versus load capacitance; T_{amb} = 25 °C



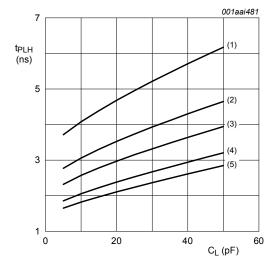
7 **t**PHL (ns) (1) 5 (2) (3) (4) (5) 3 1 0 20 40 60 C_L (pF)

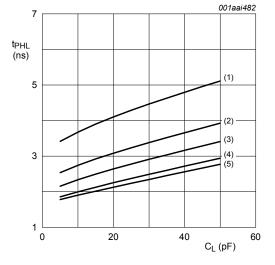




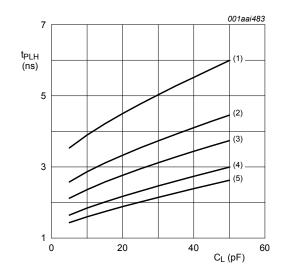
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4-bit dual supply translating transceiver; 3-state

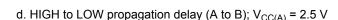




a. LOW to HIGH propagation delay (A to B); $V_{CC(A)} = 1.8 \text{ V}$



c. LOW to HIGH propagation delay (A to B); V_{CC(A)} = 2.5 V d. HIGH to LOW propagation delay (A to B); V_{CC(A)} = 2.5 V

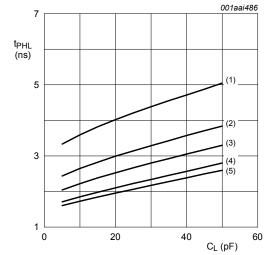


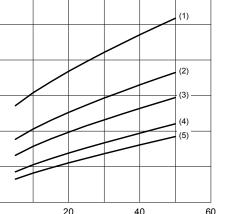
(1) $V_{CC(B)} = 1.2 V$

- (2) V_{CC(B)} = 1.5 V (3) V_{CC(B)} = 1.8 V
- (4) V_{CC(B)} = 2.5 V
- (5) V_{CC(B)} = 3.3 V

Figure 9. Typical propagation delay versus load capacitance; T_{amb} = 25 °C

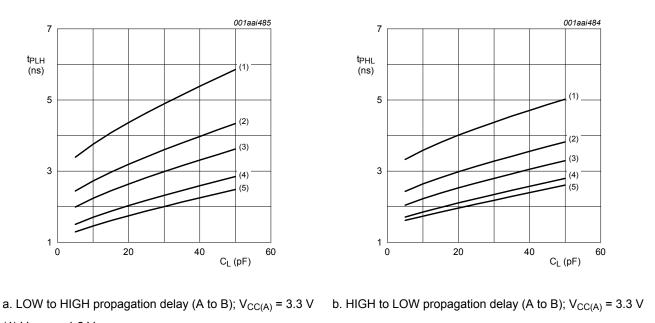
b. HIGH to LOW propagation delay (A to B); V_{CC(A)} = 1.8 V





74AVC4T774PW

4-bit dual supply translating transceiver; 3-state



(1) V_{CC(B)} = 1.2 V

(2) V_{CC(B)} = 1.5 V

(3) V_{CC(B)} = 1.8 V

(4) V_{CC(B)} = 2.5 V

(5) $V_{CC(B)}$ = 3.3 V

Figure 10. Typical propagation delay versus load capacitance; T_{amb} = 25 °C

19 / 24

4-bit dual supply translating transceiver; 3-state

12 Package outline

	6: pia	stic th	nin sh	rink s	mall	outlin	e pacl	kage;	16 lea	ids; b	ody v	vidth 4	I.4 m	m			S	OT40:
		t			- D				c			— E -				X)	Ą	
				Z pin 1			1	w (M)			↓ ↓ ↓		L- L-		(A3) • • • • •	A U θ		
IMENS	IONS (n	nm are t	the orig	jinal din	nension	s)	0		2.5 scale		5 mm							
DIMENS	IONS (n A max.	nm are t A ₁	the orig	jinal din	nension b _p	s) C	0 	E (2)		HE	5 mm	Lp	Q	v	w	У	Z ⁽¹⁾	θ
	Α					-		E (2) 4.5 4.3	scale	Н _Е 6.6 6.2			Q 0.4 0.3	v 0.2	w 0.13	y 0.1	Z (1) 0.40 0.06	θ 8° 0°
UNIT mm lotes . Plastic . Plastic	A max. 1.1 c or meta c interlea	A ₁ 0.15 0.05	A ₂ 0.95 0.80	Α3	b p 0.30 0.19 m maxin	c 0.2 0.1	D (1) 5.1 4.9 side ard	4.5 4.3	e 0.65 luded.	6.6	L	L _p 0.75	0.4	0.2	0.13	0.1	0.40 0.06	8° 0°
UNIT mm lotes . Plastic . Plastic UL VE	A max. 1.1 c or meta	A ₁ 0.15 0.05	A ₂ 0.95 0.80 sions of usions o	A ₃ 0.25	b p 0.30 0.19 m maxin	c 0.2 0.1	D (1) 5.1 4.9 side ard r side ar REFE	4.5 4.3 e not inc e not inc	e 0.65 luded.	6.6	L	L _p 0.75	0.4	0.2	0.13	0.1	0.40	8° 0°

74AVC4T774PW
Product data sheet

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4-bit dual supply translating transceiver; 3-state

13 Abbreviations

Table 17. Abbreviations							
Acronym	Description						
CDM	Charged Device Model						
DUT	Device Under Test						
ESD	ElectroStatic Discharge						
НВМ	Human Body Model						

14 Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AVC4T774PW v.1	20170925	Product sheet	-	-

4-bit dual supply translating transceiver; 3-state

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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22 / 24

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74AVC4T774PW

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Contents

1	General description	1
2	Features and benefits	1
3	Ordering information	2
4	Marking	
5	Functional diagram	
6	Pinning information	3
6.1	Pinning	
6.2	Pin description	
7	Functional description	
8	Limiting values	4
9	Recommended operating conditions	5
10	Static characteristics	
11	Dynamic characteristics	9
11.1	Waveforms and test circuit	
11.2	Typical propagation delay characteristics	16
12	Package outline	
13	Abbreviations	
14	Revision history	
15	Legal information	

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